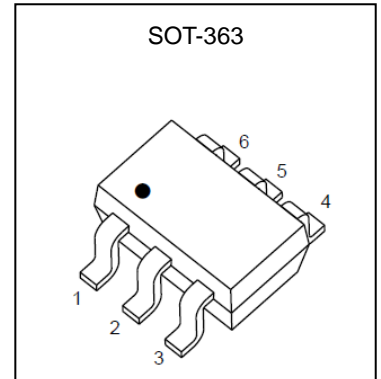


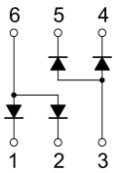
BAT54ADW/BRW/CDW/SDW/DW/JW Schottky Barrier Diode

Feature

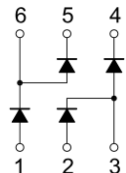
- Extremely Fast Switch Speed
- Low Forward Voltage
- Small Surface Mount Package



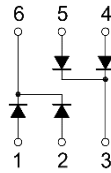
MARKING:



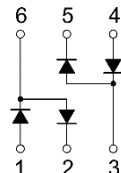
BAT54ADW



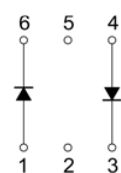
BAT54BRW



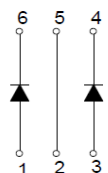
BAT54CDW



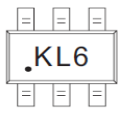
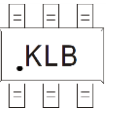
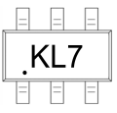
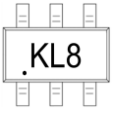
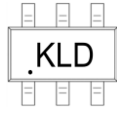
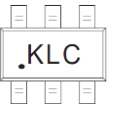
BAT54SDW



BAT54DW



BAT54JW

BAT54ADW	BAT54BRW	BAT54CDW	BAT54SDW	BAT54DW	BAT54JW
					

Solid dot = Pin1 indicate.

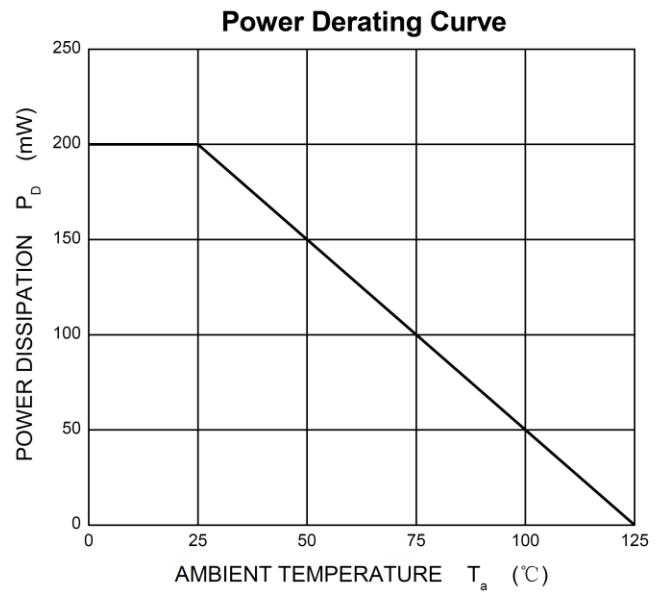
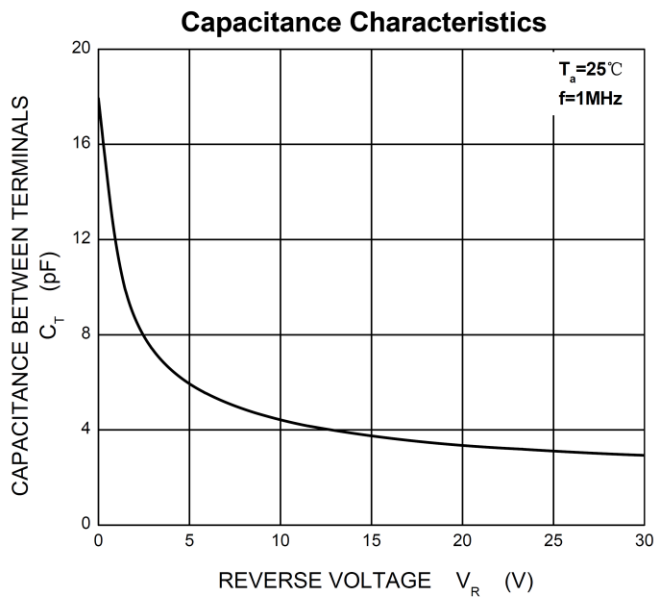
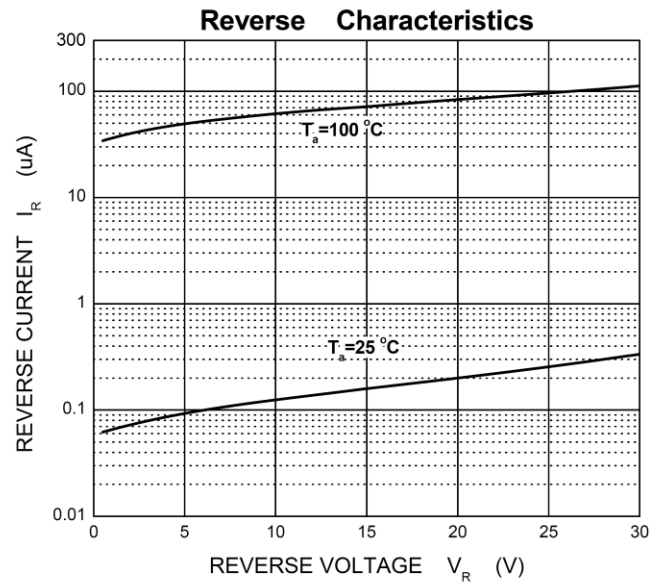
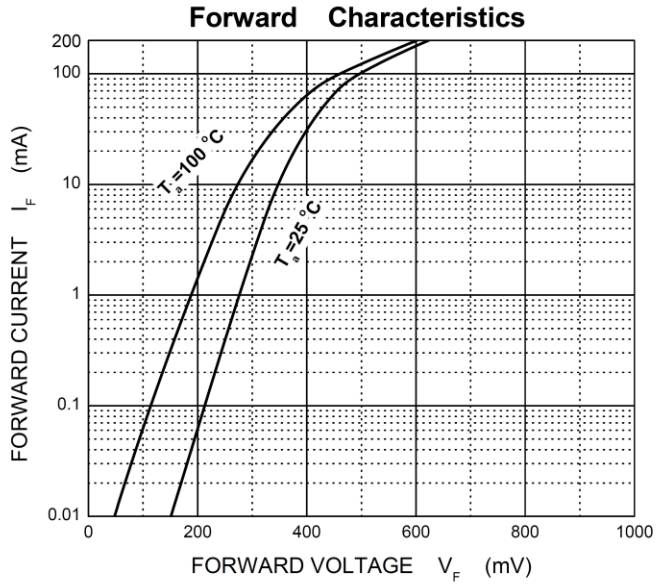
ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
DC reverse voltage	V_R	30	V
Mean rectifying current	I_O	0.2	A
Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	I_{FSM}	0.6	A
Power Dissipation	P_D	0.2	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	500	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	125	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^{\circ}\text{C}$

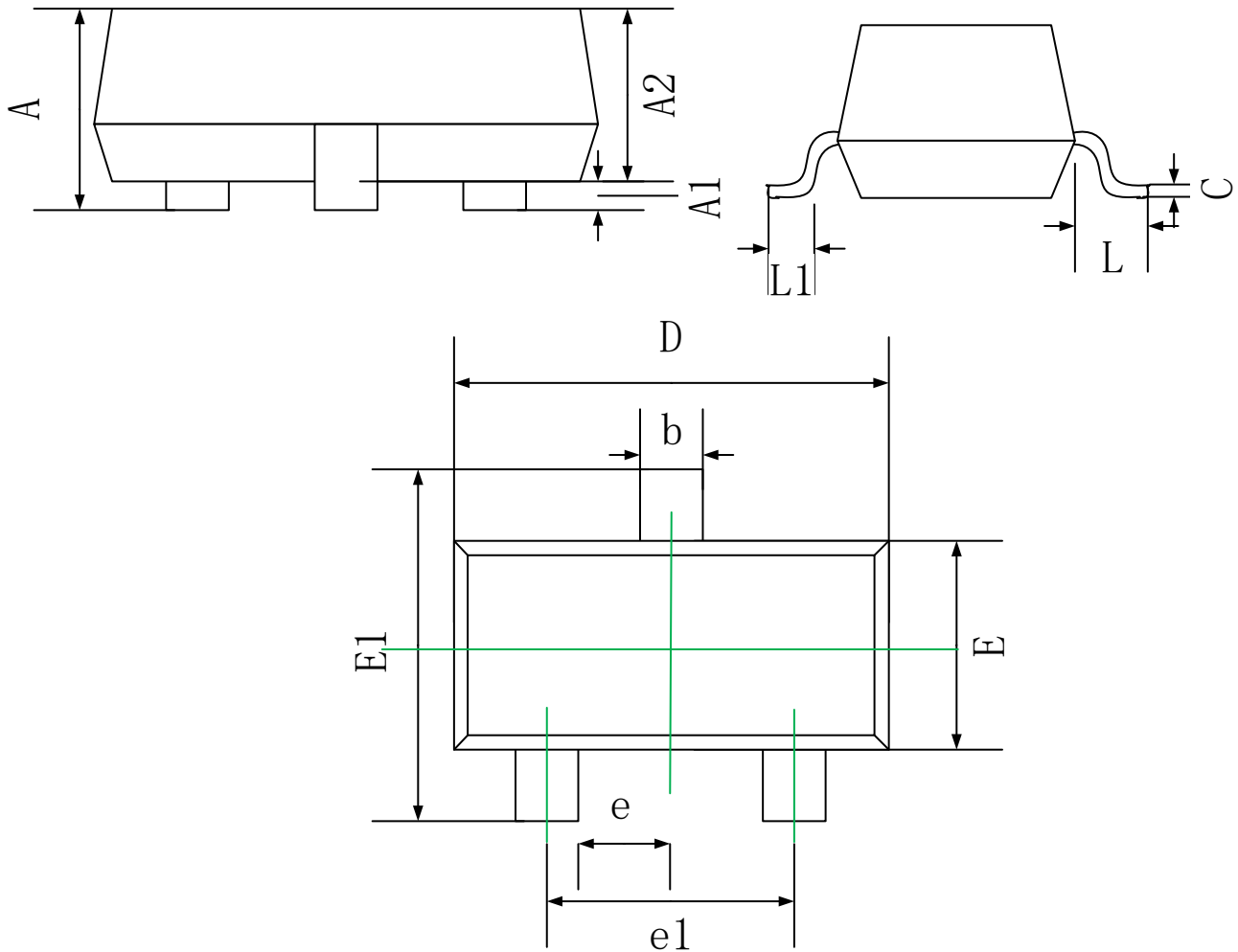
ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	30			V
Forward voltage	V_{F1}	$I_F=0.1\text{mA}$			0.24	V
	V_{F2}	$I_F=1\text{mA}$			0.32	V
	V_{F3}	$I_F=10\text{mA}$			0.40	V
	V_{F4}	$I_F=30\text{mA}$			0.50	V
	V_{F5}	$I_F=100\text{mA}$			1	V
Reverse current	I_R	$V_R=25\text{V}$			2	μA
Reverse recovery time	t_{rr}	$I_F=I_R=10\text{mA}$, $I_{rr}=0.1^* I_R$, $R_L=100\Omega$			5	ns
Capacitance between terminals	C_T	$V_R=1\text{V}$, $f=1\text{MHz}$			10	pF

Typical Characteristics



SOT-363 Package Outline Dimensions



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.90	1.10
A1	0.00	0.10
A2	0.90	1.00
b	0.15	0.35
c	0.10	0.15
D	2.00	2.20
E	1.15	1.35
E1	2.15	2.40
e	0.65 TYP.	
e1	1.20	1.40
L	0.26	0.46

单击下面可查看定价，库存，交付和生命周期等信息

[>>GP\(格瑞宝\)](#)